

SDP10U20DN

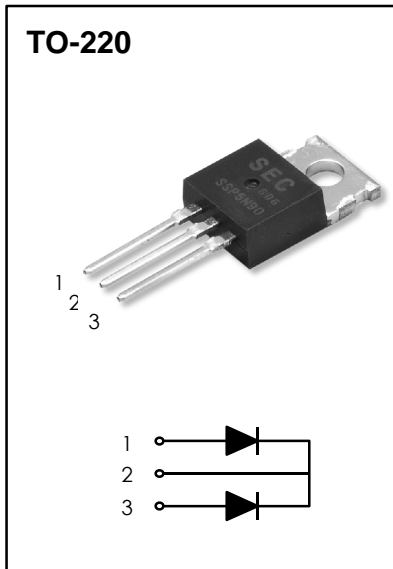
POWER RECTIFIER

FEATURES

- * Ultrafast with Soft Recovery
($T_{rr} < 35\text{ns}$)
- * Low Forward Voltage ($V_F=0.98\text{V}$ at $I_F=10\text{A}$)

APPLICATIONS

- * Power Switching Circuits
- * Output rectifiers
- * Freewheeling Diodes
- * Switching Mode Power Supply



MAXIMUM RATINGS

| Rating | Symbol | Value | Units |
|--|----------------|-----------|------------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | 200 | V |
| Average Rectified Forward Current, $T_C=100\text{ }^\circ\text{C}$ | $I_{F(AV)}$ | 10 | A |
| Non-repetitive Peak Surge Current (Half-wave, Single Phase, 60Hz) | I_{FSM} | 100 | A |
| Operating Junction and Storage Temperature | T_J, T_{STG} | -65 ~ 150 | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| | | | |
|---------------------------------------|-----------------|-----|--------------------|
| Thermal Resistance - Junction to Case | $R_{\theta JC}$ | 4.5 | $^\circ\text{C/W}$ |
|---------------------------------------|-----------------|-----|--------------------|

ELECTRICAL CHARACTERISTICS

| Characteristics | Symbol | Min | Typ | Max | Units |
|--|----------------------------------|-------------|-------------|-----------------|---------------|
| Maximum Instantaneous Forward Voltage (1) ($I_F = 10A$, $T_C = 100\text{ }^\circ\text{C}$) ($I_F = 10A$, $T_C = 25\text{ }^\circ\text{C}$) | V_F | - - | - - | 1.0 1.2 | V |
| Maximum Instantaneous Reverse Current (1) (Rated DC Voltage, $T_C = 100\text{ }^\circ\text{C}$) (Rated DC Voltage, $T_C = 25\text{ }^\circ\text{C}$) | I_R | - - | - - | 100 10 | μA |
| Maximum Reverse Recovery Time ($I_F = 10A$, $di/dt = -200A/\mu\text{s}$) | t_{rr} I_{rr} Q_{rr} | - - - | - - - | 35 2.5 45 | ns A nC |
| Avalanche Energy | W_{AVL} | 0.5 | - | - | mJ |

(1) Pulse Test : Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

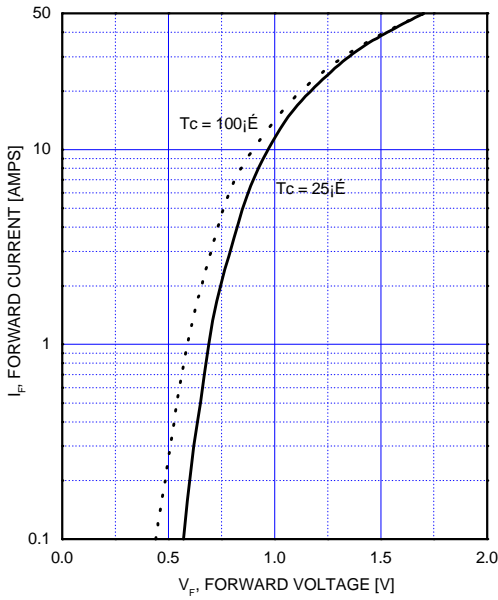


Fig.1 Typical Forward Voltage Drop vs. Forward Current

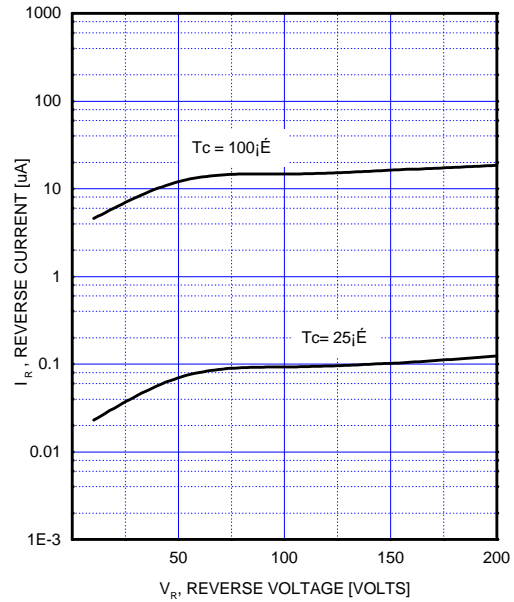


Fig.2 Reverse Voltage vs. Reverse Current

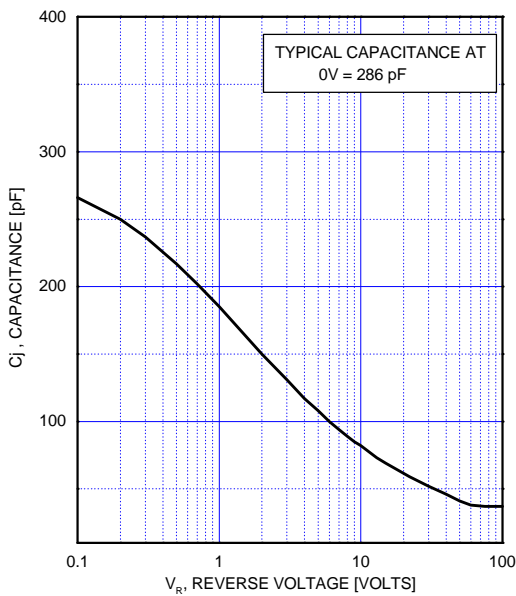


Fig.3 Typical Capacitance

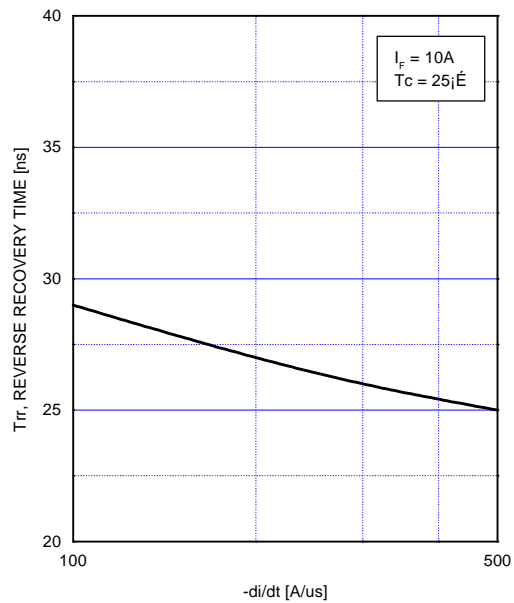


Fig.4 Typical Reverse Recovery Time vs. di/dt

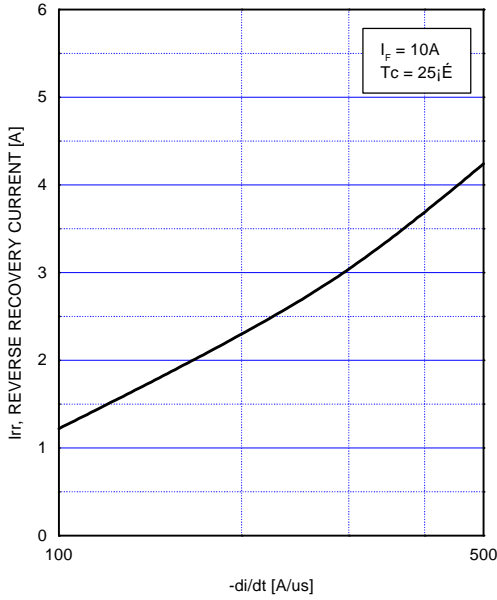


Fig.5 Typical Reverse Recovery Current vs. di/dt

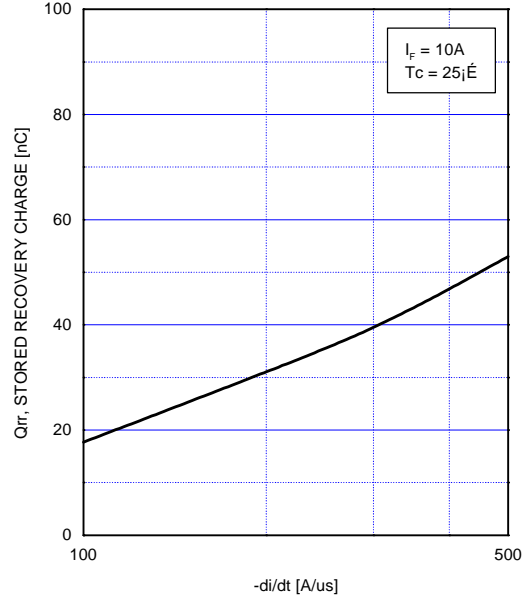


Fig.6 Typical Stored Charge vs. di/dt

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